5

15

20

(II-2)

$$R_{81}$$
 R_{82}
 $(CH_2)_{n81}$
 R_{83}

wherein, in General Formula (II-2), each of R_{81} , R_{82} , and $_{10}$ R₈₃ independently represents an alkyl group, an alkenyl group, a cycloalkyl group, or an aryl group; n81 represents 0 or 1; and at least two of R_{81} to R_{83} may be connected to each other to form a ring, and

wherein, in Formula (V), each of R₈₁, R₈₂, and R₈₃ independently represents a hydrogen atom, an alkyl group, a cycloalkyl group, a halogen atom, a cyano group, or an alkoxycarbonyl group; here, R₈₂ may be bonded to L₈ to form a ring, and R₈₂ in this case 30 represents a single bond or an alkylene group; X₈ represents a single bond or a divalent connecting group; L₈ represents a single bond or an (s+1) valent connecting group, and in the case of being bonded to R₈₂ to form a ring, represents an (s+2) valent connecting 35 group; s represents an integer of 1 to 5; here, in a case where L₈ is a single bond, s is 1; and B₈ represents a group containing a cross-linking group.

46. The active light-sensitive or radiation-sensitive resin composition according to claim 45,

wherein a cross-linking group included in B₈ in General Formula (V) is a hydroxymethyl group, an alkoxymethyl group, an oxirane ring, or an oxetane ring.

47. The active light-sensitive or radiation-sensitive resin composition according to claim 45,

wherein B₈ in General Formula (V) is a group which has a phenol structure, a urea structure, or a melamine structure, having a hydroxymethyl group or an alkoxymethyl group.

48. The active light-sensitive or radiation-sensitive resin composition according to claim 47,

wherein B₈ in General Formula (V) is a group which has a phenol structure having a hydroxymethyl group or an alkoxymethyl group, provided that the hydroxymethyl group is not directly bonded to a nitrogen atom, and the alkoxymethyl group is not directly bonded to a nitrogen atom.

49. The active light-sensitive or radiation-sensitive resin composition according to claim 45,

wherein the content of the repeating unit represented by General Formula (V) is 1 mol % to 20 mol % with respect to the entirety of repeating units in the resin (A).

50. The active light-sensitive or radiation-sensitive resin composition according to claim 45,

wherein the bond between X₄ and L₄ in General Formula (I) is a single bond.

51. The active light-sensitive or radiation-sensitive resin composition according to claim 45,

wherein the content of the repeating unit represented by General Formula (I) is 10 mol % to 40 mol % with respect to the entirety of repeating units in the resin (A).

52. The active light-sensitive or radiation-sensitive resin composition according to claim 45,

wherein the active light-sensitive or radiation-sensitive resin composition further includes a compound (B) that generates an acid by active light or radiation.

53. The active light-sensitive or radiation-sensitive resin composition according to claim 52,

wherein the compound (B) that generates an acid by active light or radiation is a compound that generates an acid having a volume of 240 Angstroms³ or greater.

54. A resist film which is formed using the active lightsensitive or radiation-sensitive resin composition according to claim 45.